

#### SNOSAU9D - MARCH 2006 - REVISED MARCH 2013

# LMV796/LMV796Q/LMV797 17 MHz, Low Noise, CMOS Input, 1.8V Operational Amplifiers

Check for Samples: LMV796, LMV797

## **FEATURES**

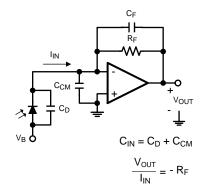
(Typical 5V Supply, Unless Otherwise Noted)

- Input Referred Voltage Noise 5.8 nV/√Hz
- Input Bias Current 100 fA
- Unity Gain Bandwidth 17 MHz
- Supply Current per Channel
  - LMV796/LMV796Q 1.15 mA
    - LMV797 1.30 mA
- Rail-to-Rail Output Swing
  - @ 10 k $\Omega$  Load 25 mV from Rail
  - @ 2 k $\Omega$  Load 45 mV from Rail
- Guaranteed 2.5V and 5.0V Performance
- Total Harmonic Distortion 0.01% @ 1kHz, 600Ω
- Temperature Range -40°C to 125°C
- LMV796Q is an Automotive Grade Product that is AEC-Q100 Grade 1 Qualified and is Manufactured on an Automotive Grade Flow.

## **APPLICATIONS**

- Photodiode Amplifiers
- Active Filters and Buffers
- Low Noise Signal Processing
- Medical Instrumentation
- Sensor Interface Applications
- Automotive

### **Typical Application**



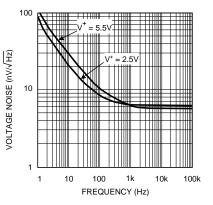
#### Figure 1. Photodiode Transimpedance Amplifier

## DESCRIPTION

The LMV796/LMV796Q (Single) and the LMV797 (Dual) low noise, CMOS input operational amplifiers offer a low input voltage noise density of 5.8 nV/ $\sqrt{\text{Hz}}$  while consuming only 1.15 mA (LMV796/LMV796Q) of quiescent current. The LMV796/LMV796Q and LMV797 are unity gain stable op amps and have gain bandwidth of 17 MHz. The LMV796/LMV796Q/LMV797 have a supply voltage range of 1.8V to 5.5V and can operate from a single supply. The LMV796/LMV796Q/LMV796Q/LMV797 each feature a rail-to-rail output stage capable of driving a 600 $\Omega$  load and sourcing as much as 60 mA of current.

The LMV796/LMV796Q family provides optimal performance in low voltage and low noise systems. A CMOS input stage, with typical input bias currents in the range of a few femtoAmperes, and an input common mode voltage range, which includes ground, make the LMV796/LMV796Q and the LMV797 ideal for low power sensor applications.

The LMV796/LMV796Q/LMV797 are manufactured using TI's advanced VIP50 process. The LMV796/ LMV796Q are offered in 5–pin SOT-23 package. The LMV797 is offered in 8–pin VSSOP package.





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# LMV796, LMV797

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### Absolute Maximum Ratings<sup>(1)(2)</sup>

|                                     | Human Body Model                         | 2000V                                      |
|-------------------------------------|--|--|
| ESD Tolerance <sup>(3)</sup>        | Machine Model                            | 200V                                       |
|                                     | Charge-Device Model                      | 1000V                                      |
| V <sub>IN</sub> Differential        |  | ±0.3V                                      |
| Supply Voltage $(V^+ - V^-)$        | 6.0V                                     |  |
| Input/Output Pin Voltage            |  | V <sup>+</sup> +0.3V, V <sup>−</sup> −0.3V |
| Storage Temperature Range           |  | -65°C to 150°C                             |
| Junction Temperature <sup>(4)</sup> |  | +150°C                                     |
| Coldoring Information               | Infrared or Convection (20 sec)          | 235°C                                      |
| Soldering Information               | Wave Soldering Lead Temperature (10 sec) | 260°C                                      |

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics tables.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

(3) Human Body Model is  $1.5k\Omega$  in series with 100pF. Machine Model is  $0\Omega$  in series with 200pF.

(4) The maximum power dissipation is a function of  $T_{JMAX}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{JMAX} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC Board.

### Operating Ratings<sup>(1)</sup>

| Temperature Range <sup>(2)</sup>                  |   | -40°C to 125°C |
|---|---|----------------|
| Supply (1/2)                                      | $-40^{\circ}C \le T_{A} \le 125^{\circ}C$ | 2.0V to 5.5V   |
| Supply Voltage (V <sup>+</sup> – V <sup>-</sup> ) | $0^{\circ}C \le T_{A} \le 125^{\circ}C$   | 1.8V to 5.5V   |
| Package Thermal Resistance $(\theta_{JA})^{(2)}$  | 5-Pin SOT-23                              | 180°C/W        |
|   | 8-Pin VSSOP                               | 236°C/W        |

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the *Electrical Characteristics* tables.

(2) The maximum power dissipation is a function of  $T_{JMAX}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{JMAX} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC Board.

### 2.5V Electrical Characteristics

Unless otherwise specified, all limits are specified for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2 = V_0$ . Boldface limits apply at the temperature extremes.

| Symbol                       | Parameter   | Con  | ditions   | Min<br>(1) | Тур<br>(2) | Max<br>(1)            | Units |
|------------------------------|---|--|---|------------|------------|-----------------------|-------|
| V <sub>OS</sub>              | Input Offset Voltage                                      |  |   |            | 0.1        | ±1.35<br><b>±1.65</b> | mV    |
| TOV                          | TC V <sub>OS</sub> Input Offset Voltage Temperature Drift | LMV796/LMV796Q <sup>(3)</sup>                        |   | -1.0       |            |                       |       |
| IC V <sub>OS</sub>           |   | LMV797 <sup>(3)</sup>                                |   | -1.8       |            | μV/°C                 |       |
|                              |   | V <sub>CM</sub> = 1.0V <sup>(4)</sup> <sup>(5)</sup> | -40°C ≤ T <sub>A</sub> ≤ 85°C   |            | 0.05       | 1<br><b>25</b>        | -     |
| I <sub>B</sub> Input Bias Cu | Input Bias Current  | $V_{CM} = 1.0V^{(1)}$                                | $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 125^{\circ}\text{C}$ |            | 0.05       | 1<br><b>100</b>       | рА    |
| I <sub>OS</sub>              | Input Offset Current                                      | $V_{CM} = 1.0V^{(5)}$                                |   |            | 10         |                       | fA    |

(1) Limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlations using the statistical quality control (SQC) method.

(2) Typical values represent the parametric norm at the time of characterization.

- (3) Offset voltage average drift is determined by dividing the change in V<sub>OS</sub> by temperature change.
- (4) Positive current corresponds to current flowing into the device.
- (5) This parameter is specified by design and/or characterization and is not tested in production.
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### 2.5V Electrical Characteristics (continued)

Unless otherwise specified, all limits are specified for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2 = V_0$ . Boldface limits apply at the temperature extremes.

| Symbol           | Parameter  | Conditions   |   | Min<br>(1)           | Тур<br>(2) | Max<br>(1)          | Units       |
|------------------|--|--|---|----------------------|------------|---------------------|-------------|
| CMRR             | Common Mode Rejection Ratio  | $0V \le V_{CM} \le 1.4V$   | $0V \le V_{CM} \le 1.4V$                          |                      | 94         |                     | dB          |
| PSRR             | Power Supply Rejection Ratio   | $2.0V \le V^+ \le 5.5V, V_{CM}$  | = 0V  | 80<br><b>75</b>      | 100        |                     | dB          |
|                  |  | $1.8V \le V^+ \le 5.5V, V_{CM}$  | = 0V  | 80                   | 98         |                     |             |
| CMVR             | Common Mode Voltage Range  | CMRR ≥ 60 dB<br>CMRR ≥ 55 dB   |   | -0.3<br>- <b>0.3</b> |            | 1.5<br><b>1.5</b>   | V           |
|                  |  | $V_{OUT} = 0.15V$ to 2.2V,   | LMV796/LMV796Q                                    | 85<br><b>80</b>      | 98         |                     |             |
| A <sub>VOL</sub> | Open Loop Voltage Gain   | $R_{LOAD} = 2 k\Omega \text{ to } V^+/2$                               | LMV797  | 82<br><b>78</b>      | 92         |                     | dB          |
|                  | $V_{OUT} = 0.15V \text{ to } 2.2V,$<br>$R_{LOAD} = 10 \text{ k}\Omega \text{ to } V^+/2$ |  | 88<br><b>84</b>                                   | 110                  |            |                     |             |
|                  |  | $R_{LOAD} = 2 k\Omega \text{ to } V^+/2$                               |   |                      | 25         | 75<br><b>82</b>     |             |
|                  | Output Voltage Swing High  | $R_{LOAD} = 10 \text{ k}\Omega \text{ to V}^+/2$                       | $R_{LOAD} = 10 \text{ k}\Omega \text{ to } V^+/2$ |                      |            | 65<br><b>71</b>     | mV from     |
| V <sub>OUT</sub> |  | $R_{LOAD} = 2 k\Omega$ to V <sup>+</sup> /2                            |   |                      | 30         | 75<br><b>78</b>     | either rail |
|                  | Output Voltage Swing Low   | $R_{LOAD} = 10 \text{ k}\Omega \text{ to V}^+/2$                       |   |                      | 15         | 65<br><b>67</b>     |             |
|                  |  | Sourcing to V <sup>-</sup><br>V <sub>IN</sub> = 200 mV <sup>(6)</sup>  |   | 35<br><b>28</b>      | 47         |                     |             |
| IOUT             | Output Current   | Sinking to V <sup>+</sup><br>V <sub>IN</sub> = $-200 \text{ mV}^{(6)}$ |   | 7<br>5               | 15         |                     | - mA        |
|                  |  | LMV796/LMV796Q   |   |                      | 0.95       | 1.30<br><b>1.65</b> |             |
| I <sub>S</sub>   | Supply Current per Amplifier   | LMV797<br>per channel  |   |                      | 1.1        | 1.50<br><b>1.85</b> | - mA        |
| 00               | Claur Data   | $A_V = +1$ , Rising (10% t   | o 90%)  |                      | 8.5        |                     | N//         |
| SR               | Slew Rate  | $A_V = +1$ , Falling (90%)   |   | 10.5                 |            | - V/μs              |             |
| GBW              | Gain Bandwidth   |  |   |                      | 14         |                     | MHz         |
| e <sub>n</sub>   | Input Referred Voltage Noise Density   | f = 1 kHz  |   |                      | 6.2        |                     | nV/√Hz      |
| i <sub>n</sub>   | Input Referred Current Noise Density   | f = 1 kHz  |   |                      | 0.01       |                     | pA/√Hz      |
| THD+N            | Total Harmonic Distortion + Noise  | $f = 1 \text{ kHz}, A_V = 1, R_{LOA}$                                  | $A_D = 600\Omega$                                 |                      | 0.01       |                     | %           |

(6) The short circuit test is a momentary test, the short circuit duration is 1.5ms.

### **5V Electrical Characteristics**

Unless otherwise specified, all limits are specified for  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2 = V_0$ . Boldface limits apply at the temperature extremes.

| Symbol             | Parameter                              | Conditions                    | <b>Min</b><br>(1) | <b>Typ</b><br>(2) | <b>Max</b><br>(1)     | Units |
|--------------------|--|-------------------------------|-------------------|-------------------|-----------------------|-------|
| V <sub>OS</sub>    | Input Offset Voltage                   |                               |                   | 0.1               | ±1.35<br><b>±1.65</b> | mV    |
| TOV                | Innut Offeet Veltere Temperature Drift | LMV796/LMV796Q <sup>(3)</sup> |                   | -1.0              |                       |       |
| TC V <sub>OS</sub> | Input Offset Voltage Temperature Drift | LMV797 <sup>(3)</sup>         |                   | -1.8              |                       | µV/°C |

 Limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlations using the statistical quality control (SQC) method.

- (2) Typical values represent the parametric norm at the time of characterization.
- (3) Offset voltage average drift is determined by dividing the change in V<sub>OS</sub> by temperature change.



### 5V Electrical Characteristics (continued)

Unless otherwise specified, all limits are specified for  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2 = V_O$ . Boldface limits apply at the temperature extremes.

| ine temp         | beralure extremes.                   |   |  |                      |                 |                     |                        |
|------------------|--------------------------------------|---|--|----------------------|-----------------|---------------------|------------------------|
|                  | lanut Ding Current                   | $V_{CM} = 2.0V^{(4)}$ (5)   | $-40^{\circ}C \le T_A \le 85^{\circ}C$ |                      | 0.1             | 1<br><b>25</b>      | - 4                    |
| IB               | Input Bias Current                   | $-40^{\circ}C \le T_{A} \le 125^{\circ}C$   |  |                      | 0.1             | 1<br><b>100</b>     | – pA                   |
| l <sub>os</sub>  | Input Offset Current                 | $V_{CM} = 2.0V^{(5)}$   |  |                      | 10              |                     | fA                     |
| CMRR             | Common Mode Rejection Ratio          | $0V \le V_{CM} \le 3.7V$  |  | 80<br><b>75</b>      | 100             |                     | dB                     |
| PSRR             | Power Supply Rejection Ratio         | $2.0V \le V^+ \le 5.5V, V_{CM}$   | $2.0V \le V^+ \le 5.5V, V_{CM} = 0V$   |                      | 100             |                     | dB                     |
|                  |                                      | 1.8V ≤ V <sup>+</sup> ≤ 5.5V, V <sub>CM</sub>                                       | = 0V                                   | 80                   | 98              |                     |                        |
| CMVR             | Common Mode Voltage Range            | CMRR ≥ 60 dB<br>CMRR ≥ 55 dB  |  | -0.3<br>- <b>0.3</b> |                 | 4<br><b>4</b>       | V                      |
|                  |                                      | V <sub>OUT</sub> = 0.3V to 4.7V,  | LMV796/LMV796Q                         | 85<br><b>80</b>      | 97              |                     |                        |
| A <sub>VOL</sub> | Open Loop Voltage Gain               | $R_{LOAD} = 2 k\Omega \text{ to } V^+/2$  | LMV797                                 | 82<br><b>78</b>      | 89              |                     | dB                     |
|                  |                                      | $V_{OUT} = 0.3V$ to 4.7V,<br>R <sub>LOAD</sub> = 10 k $\Omega$ to V <sup>+</sup> /2 |  | 88<br><b>84</b>      | 110             |                     |                        |
|                  |                                      | $R_{LOAD} = 2 k\Omega$ to V <sup>+</sup> /2   |  | 35                   | 75<br><b>82</b> |                     |                        |
| Ou               | Output Voltage Swing High            | $R_{LOAD} = 10 \text{ k}\Omega \text{ to V}^+/2$                                    |  |                      | 25              | 65<br><b>71</b>     |                        |
| V <sub>OUT</sub> | т                                    |   | LMV796/LM796Q                          |                      | 42              | 75<br><b>78</b>     | mV from<br>either rail |
|                  | Output Voltage Swing Low             | $R_{LOAD} = 2 k\Omega \text{ to } V^+/2$  | LMV797                                 |                      | 45              | 80<br><b>83</b>     | _                      |
|                  |                                      | $R_{LOAD} = 10 \text{ k}\Omega \text{ to V}^+/2$                                    |  | 20                   | 65<br><b>67</b> |                     |                        |
|                  |                                      | Sourcing to V <sup>-</sup><br>V <sub>IN</sub> = 200 mV <sup>(6)</sup>               |  | 45<br><b>37</b>      | 60              |                     |                        |
| I <sub>OUT</sub> | Output Current                       | Sinking to V <sup>+</sup><br>V <sub>IN</sub> = $-200 \text{ mV}^{(6)}$              |  | 10<br><b>6</b>       | 21              |                     | - mA                   |
|                  |                                      | LMV796/LMV796Q  |  |                      | 1.15            | 1.40<br><b>1.75</b> |                        |
| I <sub>S</sub>   | Supply Current per Amplifier         | LMV797per channel   |  |                      | 1.30            | 1.70<br><b>2.05</b> | – mA                   |
| SR               | Slew Rate                            | $A_V = +1$ , Rising (10%)   | to 90%)                                | 6.0                  | 9.5             |                     | V/µs                   |
| SK               |                                      | $A_V = +1$ , Falling (90%)  | to 10%)                                | 7.5                  | 11.5            |                     | v/µs                   |
| GBW              | Gain Bandwidth                       |   |  |                      | 17              |                     | MHz                    |
| e <sub>n</sub>   | Input Referred Voltage Noise Density | f = 1 kHz   |  |                      | 5.8             |                     | nV/√Hz                 |
| i <sub>n</sub>   | Input Referred Current Noise Density | f = 1 kHz   |  |                      | 0.01            |                     | pA/√Hz                 |
| THD+N            | Total Harmonic Distortion + Noise    | $f = 1 \text{ kHz}, A_V = 1, R_{LO}$  | <sub>AD</sub> = 600Ω                   |                      | 0.01            |                     | %                      |

(4) Positive current corresponds to current flowing into the device.

This parameter is specified by design and/or characterization and is not tested in production. The short circuit test is a momentary test, the short circuit duration is 1.5ms. (5)

(6)



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## **Connection Diagram**

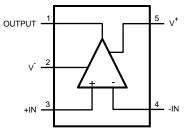


Figure 3. 5-Pin SOT-23 Top View

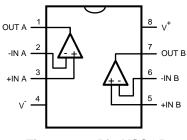
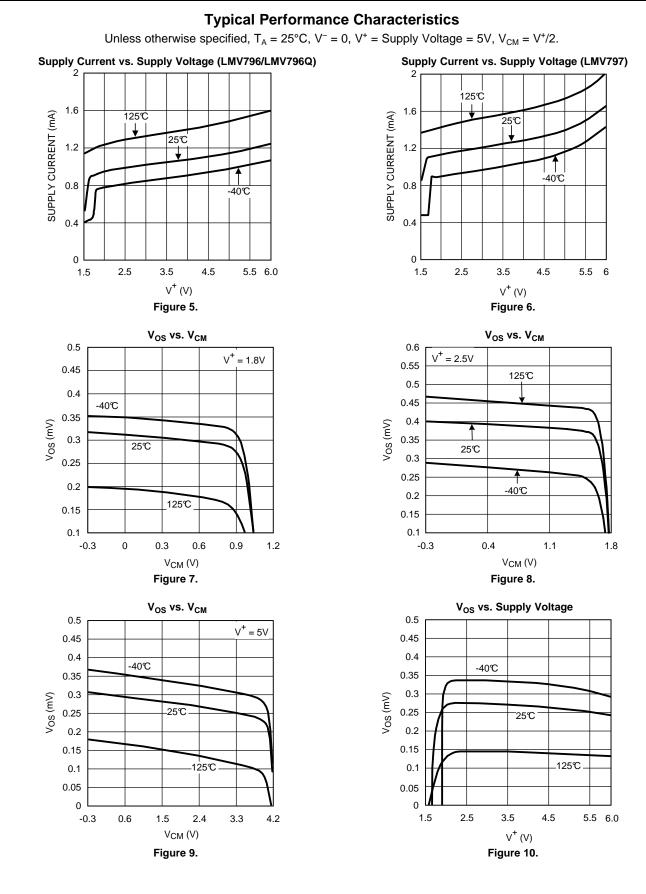


Figure 4. 8-Pin VSSOP Top View

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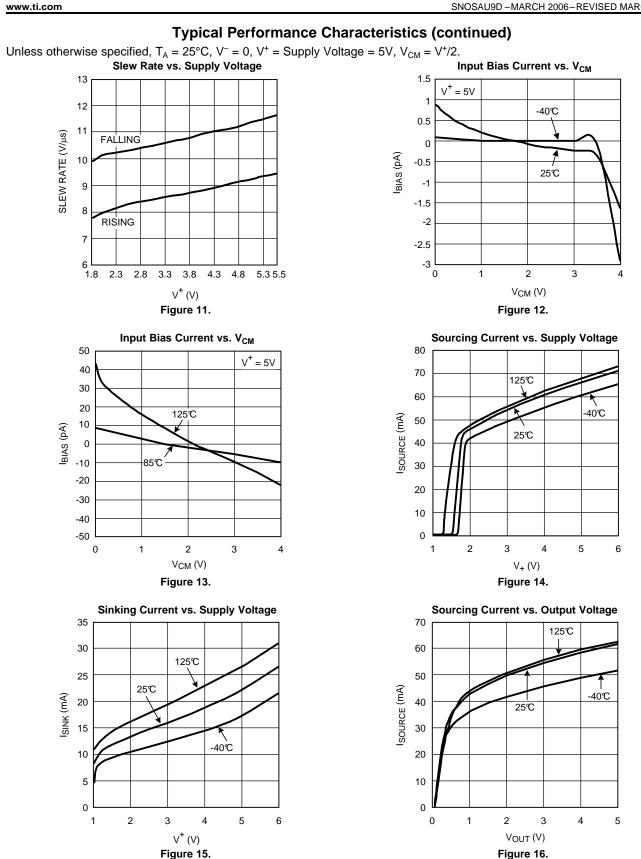


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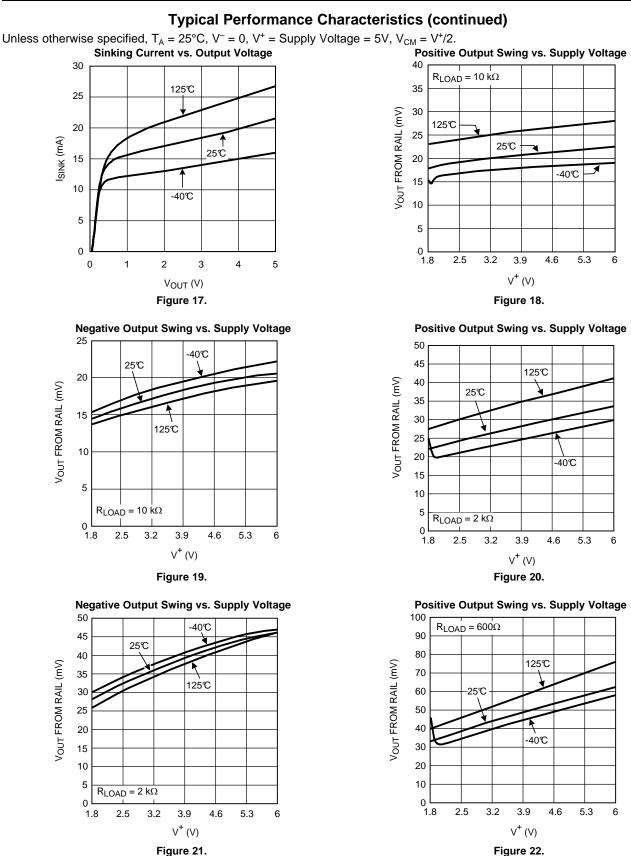
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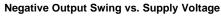


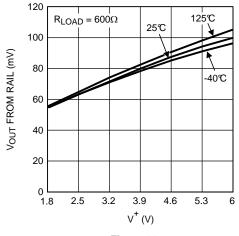
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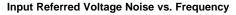
## **Typical Performance Characteristics (continued)**

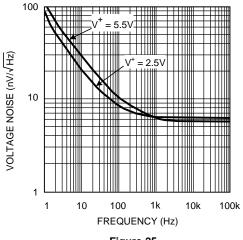
Unless otherwise specified,  $T_A = 25^{\circ}C$ ,  $V^- = 0$ ,  $V^+ = Supply Voltage = 5V$ ,  $V_{CM} = V^+/2$ .





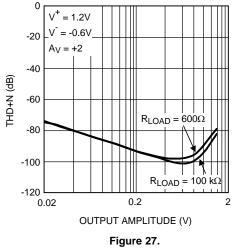
#### Figure 23.







THD+N vs. Peak-to-Peak Output Voltage (VOUT)



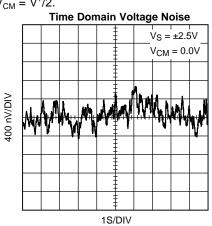
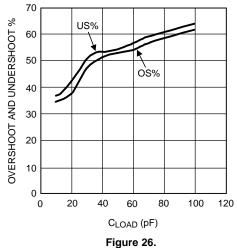
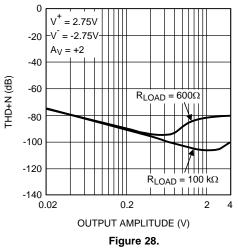


Figure 24.

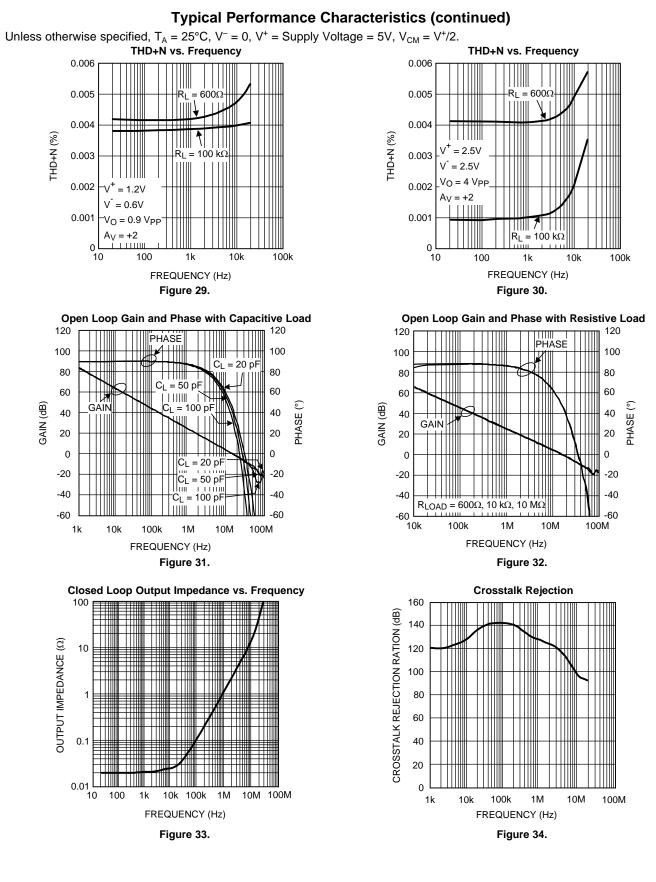
Overshoot and Undershoot vs. CLOAD



THD+N vs. Peak-to-Peak Output Voltage (VOUT)



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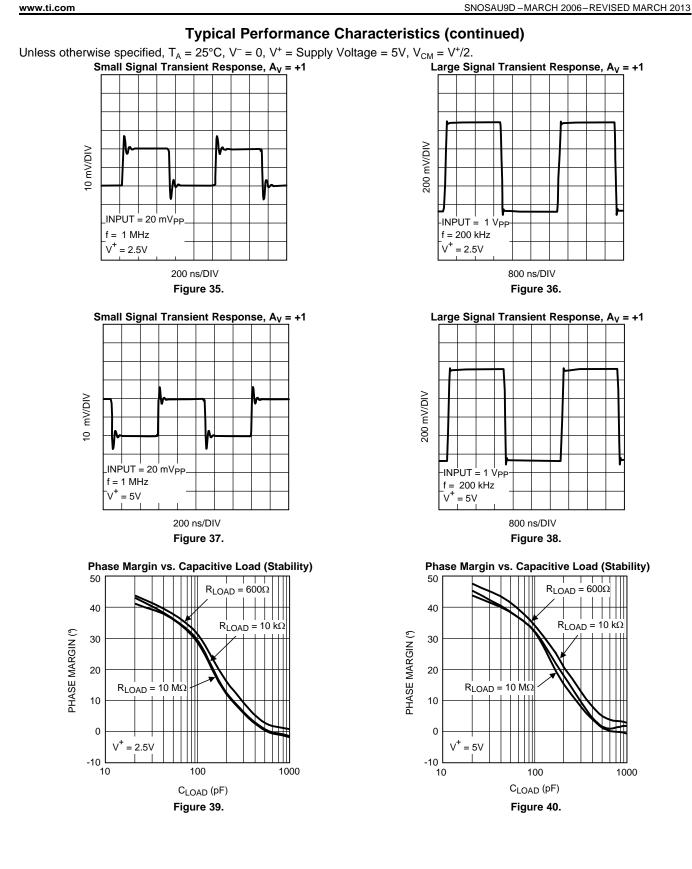


ISTRUMENTS

EXAS

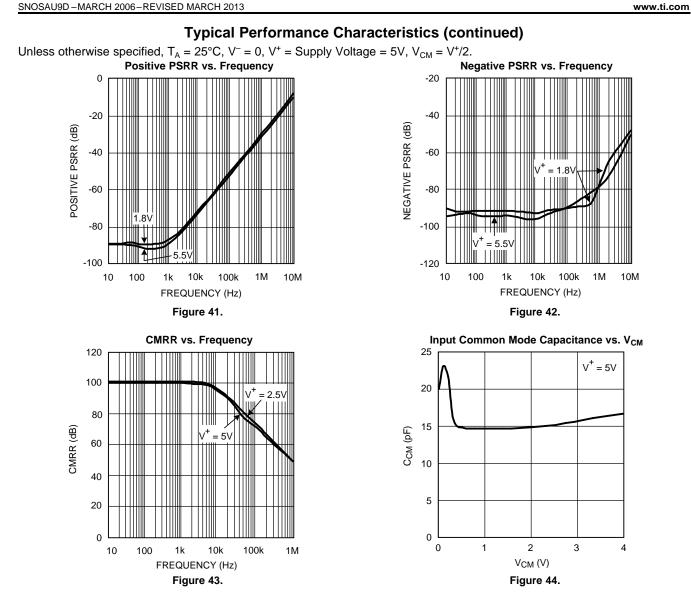


## LMV796, LMV797



EXAS **ISTRUMENTS** 

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### **APPLICATION INFORMATION**

#### ADVANTAGES OF THE LMV796/LMV797

#### Wide Bandwidth at Low Supply Current

The LMV796 and LMV797 are high performance op amps that provide a unity gain bandwidth of 17 MHz while drawing a low supply current of 1.15 mA. This makes them ideal for providing wideband amplification in portable applications.

#### Low Input Referred Noise and Low Input Bias Current

The LMV796/LMV797 have a very low input referred voltage noise density (5.8 nV/ $\sqrt{\text{Hz}}$  at 1 kHz). A CMOS input stage ensures a small input bias current (100 fA) and low input referred current noise (0.01 pA/ $\sqrt{\text{Hz}}$ ). This is very helpful in maintaining signal fidelity, and makes the LMV796 and LMV797 ideal for audio and sensor based applications.

#### Low Supply Voltage

The LMV796 and the LMV797 have performance specified at 2.5V and 5V supply. The LMV796 family is specified to be operational at all supply voltages between 2.0V and 5.5V, for ambient temperatures ranging from -40°C to 125°C, thus utilizing the entire battery lifetime. The LMV796 and LMV797 are also specified to be operational at 1.8V supply voltage, for temperatures between 0°C and 125°C. This makes the LMV796 family ideal for usage in low-voltage commercial applications.

#### **RRO and Ground Sensing**

Rail-to-rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating at low supply voltages. An innovative positive feedback scheme is used to boost the current drive capability of the output stage. This allows the LMV796 and the LMV797 to source more than 40 mA of current at 1.8V supply. This also limits the performance of the LMV796 family as comparators, and hence the usage of the LMV796 and the LMV797 in an open-loop configuration is not recommended. The input common-mode range includes the negative supply rail which allows direct sensing at ground in single supply operation.

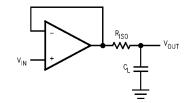
#### Small Size

The small footprint of the LMV796 and the LMV797 package saves space on printed circuit boards, and enables the design of smaller electronic products, such as cellular phones, pagers, or other portable systems. Long traces between the signal source and the op amp make the signal path susceptible to noise. By using the physically smaller LMV796 or LMV797 package, the op amp can be placed closer to the signal source, reducing noise pickup and increasing signal integrity.

#### CAPACITIVE LOAD TOLERANCE

The LMV796 and LMV797 can directly drive 120 pF in unity-gain without oscillation. The unity-gain follower is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers. The combination of the amplifier's output impedance and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation. To drive a heavier capacitive load, the circuit in Figure 45 can be used.

In Figure 45, the isolation resistor  $R_{ISO}$  and the load capacitor  $C_L$  form a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of  $R_{ISO}$ . The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. Increased  $R_{ISO}$  would, however, result in a reduced output swing and short circuit current.





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# INPUT CAPACITANCE AND FEEDBACK CIRCUIT ELEMENTS

The LMV796 family has a very low input bias current (100 fA) and a low 1/f noise corner frequency (400 Hz), which makes it ideal for sensor applications. However, to obtain this performance a large CMOS input stage is used, which adds to the input capacitance of the op amp,  $C_{IN}$ . Though this does not affect the DC and low frequency performance, at higher frequencies the input capacitance interacts with the input and the feedback impedances to create a pole, which results in lower phase margin and gain peaking. This can be controlled by being selective in the use of feedback resistors, as well as, by using a feedback capacitance,  $C_F$ . For example, in the inverting amplifier shown in Figure 46, if  $C_{IN}$  and  $C_F$  are ignored and the open loop gain of the op amp is considered infinite then the gain of the circuit is  $-R_2/R_1$ . An op amp, however, usually has a dominant pole, which causes its gain to drop with frequency. Hence, this gain is only valid for DC and low frequency. To understand the effect of the input capacitance coupled with the non-ideal gain of the op amp, the circuit needs to be analyzed in the frequency domain using a Laplace transform.

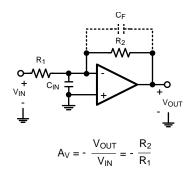


Figure 46. Inverting Amplifier

For simplicity, the op amp is modeled as an ideal integrator with a unity gain frequency of  $A_0$ . Hence, its transfer function (or gain) in the frequency domain is  $A_0$ /s. Solving the circuit equations in the frequency domain, ignoring  $C_F$  for the moment, results in an expression for the gain shown in Equation 1.

$$\frac{V_{OUT}}{V_{IN}}(s) = \frac{-R_2/R_1}{\left[1 + \frac{s}{\left(\frac{A_0 R_1}{R_1 + R_2}\right)} + \frac{s^2}{\left(\frac{A_0}{C_{IN} R_2}\right)}\right]}$$

(1)

It can be inferred from the denominator of the transfer function that it has two poles, whose expressions can be obtained by solving for the roots of the denominator and are shown in Equation 2.

$$P_{1,2} = \frac{-1}{2C_{IN}} \left[ \frac{1}{R_1} + \frac{1}{R_2} \pm \sqrt{\left(\frac{1}{R_1} + \frac{1}{R_2}\right)^2 - \frac{4A_0C_{IN}}{R_2}} \right]$$
(2)

Equation 2 shows that as the values of  $R_1$  and  $R_2$  are increased, the magnitude of the poles, and hence the bandwidth of the amplifier, is reduced. This theory is verified by using different values of  $R_1$  and  $R_2$  in the circuit shown in Figure 45 and by comparing their frequency responses. In Figure 47 the frequency responses for three different values of  $R_1$  and  $R_2$  are shown. When both  $R_1$  and  $R_2$  are 1 k $\Omega$ , the response is flattest and widest; whereas, it narrows and peaks significantly when both their values are changed to 10 k $\Omega$  or 30 k $\Omega$ . So it is advisable to use lower values of  $R_1$  and  $R_2$  to obtain a wider and flatter response. Lower resistances also help in high sensitivity circuits since they add less noise.



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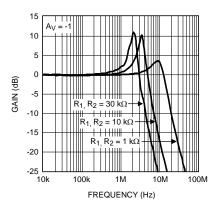


Figure 47. Gain Peaking Caused by Large R<sub>1</sub>, R<sub>2</sub>

A way of reducing the gain peaking is by adding a feedback capacitance  $C_F$  in parallel with  $R_2$ . This introduces another pole in the system and prevents the formation of pairs of complex conjugate poles which cause the gain to peak. Figure 48 shows the effect of  $C_F$  on the frequency response of the circuit. Adding a capacitance of 2 pF removes the peak, while a capacitance of 5 pF creates a much lower pole and reduces the bandwidth excessively.

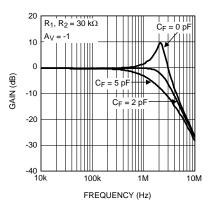


Figure 48. Gain Peaking Eliminated by C<sub>F</sub>

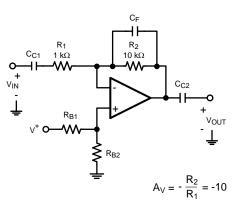
#### AUDIO PREAMPLIFIER WITH BAND PASS FILTERING

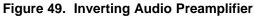
With low input referred voltage noise, low supply voltage and current, and a low harmonic distortion, the LMV796 family is ideal for audio applications. Its wide unity gain bandwidth allows it to provide large gain for a wide range of frequencies and it can be used to design a preamplifier to drive a load of as low as  $600\Omega$  with less than 0.01% distortion. Two amplifier circuits are shown in Figure 49 and Figure 50. Figure 49 is an inverting amplifier, with a 10 k $\Omega$  feedback resistor, R<sub>2</sub>, and a 1k $\Omega$  input resistor, R<sub>1</sub>, and hence provides a gain of -10. Figure 50 is a non-inverting amplifier, using the same values of R<sub>1</sub> and R<sub>2</sub>, and provides a gain of 11. In either of these circuits, the coupling capacitor C<sub>C1</sub> decides the lower frequency at which the circuit starts providing gain, while the feedback capacitor C<sub>F</sub> decides the frequency at which the gain starts dropping off. Figure 51 shows the frequency response of the inverting amplifier with different values of C<sub>F</sub>.

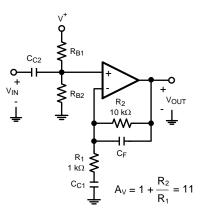
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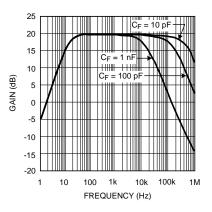


Figure 51. Frequency Response of the Inverting Audio Preamplifier

## TRANSIMPEDANCE AMPLIFIER

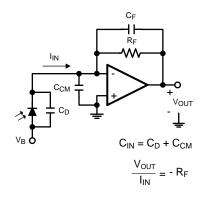
CMOS input op amps are often used in transimpedance applications as they have an extremely high input impedance. A transimpedance amplifier converts a small input current into a voltage. This current is usually generated by a photodiode. The transimpedance gain, measured as the ratio of the output voltage to the input current, is expected to be large and wide-band. Since the circuit deals with currents in the range of a few nA, low noise performance is essential. The LMV796/LMV797 are CMOS input op amps providing wide bandwidth and low noise performance, and are hence ideal for transimpedance applications.



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Usually, a transimpedance amplifier is designed on the basis of the current source driving the input. A photodiode is a very common capacitive current source, which requires transimpedance gain for transforming its miniscule current into easily detectable voltages. The photodiode and the amplifier's gain are selected with respect to the speed and accuracy required of the circuit. A faster circuit would require a photodiode with lesser capacitance and a faster amplifier. A more sensitive circuit would require a sensitive photodiode and a high gain. A typical transimpedance amplifier is shown in Figure 52. The output voltage of the amplifier is given by the equation  $V_{OUT} = -I_{IN}R_{F}$ . Since the output swing of the amplifier is limited,  $R_{F}$  should be selected such that all possible values of  $I_{IN}$  can be detected.

The LMV796/LMV797 have a large gain-bandwidth product (17 MHz), which enables high gains at wide bandwidths. A rail-to-rail output swing at 5.5V supply allows detection and amplification of a wide range of input currents. A CMOS input stage with negligible input current noise and low input voltage noise allows the LMV796/LMV797 to provide high fidelity amplification for wide bandwidths. These properties make the LMV796/LMV797 ideal for systems requiring wide-band transimpedance amplification.





As mentioned earlier, the following parameters are used to design a transimpedance amplifier: the amplifier gainbandwidth product,  $A_0$ ; the amplifier input capacitance,  $C_{CM}$ ; the photodiode capacitance,  $C_D$ ; the transimpedance gain required,  $R_F$ ; and the amplifier output swing. Once a feasible  $R_F$  is selected using the amplifier output swing, these numbers can be used to design an amplifier with the desired transimpedance gain and a maximally flat frequency response.

An essential component for obtaining a maximally flat response is the feedback capacitor,  $C_F$ . The capacitance seen at the input of the amplifier,  $C_{IN}$ , combined with the feedback capacitor,  $R_F$ , generate a phase lag which causes gain-peaking and can destabilize the circuit.  $C_{IN}$  is usually just the sum of  $C_D$  and  $C_{CM}$ . The feedback capacitor  $C_F$  creates a pole,  $f_P$  in the noise gain of the circuit, which neutralizes the zero in the noise gain,  $f_Z$ , created by the combination of  $R_F$  and  $C_{IN}$ . If properly positioned, the noise gain pole created by  $C_F$  can ensure that the slope of the gain remains at 20 dB/decade till the unity gain frequency of the amplifier is reached, thus ensuring stability. As shown in Figure 53,  $f_P$  is positioned such that it coincides with the point where the noise gain intersects the op amp's open loop gain. In this case,  $f_P$  is also the overall –3 dB frequency of the transimpedance amplifier. The value of  $C_F$  needed to make it so is given by Equation 3. A larger value of  $C_F$  causes excessive reduction of bandwidth, while a smaller value fails to prevent gain peaking and instability.

$$C_{\rm F} = \frac{1 + \sqrt{1 + 4\pi R_{\rm F} C_{\rm IN} A_0}}{2\pi R_{\rm F} A_0}$$

(3)

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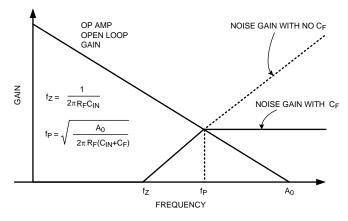
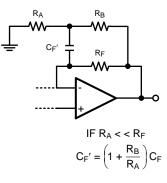


Figure 53. C<sub>F</sub> Selection for Stability

Calculating C<sub>F</sub> from Equation 3 can sometimes return unreasonably small values (<1 pF), especially for high speed applications. In these cases, it is often more practical to use the circuit shown in Figure 54 in order to allow more reasonable values. In this circuit, the capacitance C<sub>F</sub>' is  $(1 + R_B/R_A)$  times the effective feedback capacitance, C<sub>F</sub>. A larger capacitor can now be used in this circuit to obtain a smaller effective capacitance.

For example, if a C<sub>F</sub> of 0.5 pF is needed, while only a 5 pF capacitor is available, R<sub>B</sub> and R<sub>A</sub> can be selected such that R<sub>B</sub>/R<sub>A</sub> = 9. This would convert a C<sub>F</sub>' of 5 pF into a C<sub>F</sub> of 0.5 pF. This relationship holds as long as R<sub>A</sub> << R<sub>F</sub>.



#### Figure 54. Obtaining Small C<sub>F</sub> from Large C<sub>F</sub>'

#### LMV796 AS A TRANSIMPEDANCE AMPLIFIER

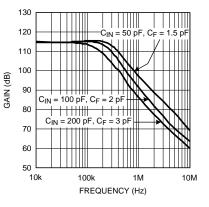
The LMV796 was used in the designs for a number of amplifiers with varying transimpedance gains and source capacitances. The gains, bandwidths and feedback capacitances of the circuits created are summarized in Table 1. The frequency responses are presented in Figure 55 and Figure 56. The feedback capacitances are slightly different from the formula in Equation 3, since the parasitic capacitance of the board and the feedback resistor  $R_F$  had to be accounted for.

| Transimpedance, A <sub>TI</sub> | C <sub>IN</sub> | C <sub>F</sub> | -3 dB Frequency |  |  |  |  |  |  |
|---------------------------------|-----------------|----------------|-----------------|--|--|--|--|--|--|
| 470000                          | 50 pF           | 1.5 pF         | 350 kHz         |  |  |  |  |  |  |
| 470000                          | 100 pF          | 2.0 pF         | 250 kHz         |  |  |  |  |  |  |
| 470000                          | 200 pF          | 3.0 pF         | 150 kHz         |  |  |  |  |  |  |
| 47000                           | 50 pF           | 4.5 pF         | 1.5 MHz         |  |  |  |  |  |  |
| 47000                           | 100 pF          | 6.0 pF         | 1 MHz           |  |  |  |  |  |  |
| 47000                           | 200 pF          | 9.0 pF         | 700 kHz         |  |  |  |  |  |  |

Table 1.



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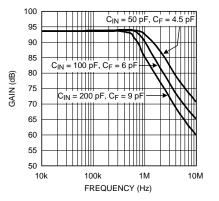


Figure 56. Frequency Response for  $A_{TI} = 47000$ 

#### HIGH GAIN WIDEBAND TRANSIMPEDANCE AMPLIFIER USING THE LMV797

The LMV797 dual, low noise, wide bandwidth, CMOS input op amp IC can be used for compact, robust and integrated solutions for sensing and amplifying wide-band signals obtained from sensitive photodiodes. One of the two op amps available can be used to obtain transimpedance gain while the other can be used for amplifying the output voltage to further enhance the transimpedance gain. The wide bandwidth of the op amps (17 MHz) ensures that they are capable of providing high gain for a wide range of frequencies. The low input referred noise (5.8 nV/ $\sqrt{Hz}$ ) allows the amplifier to deliver an output with a high SNR (signal to noise ratio). The small 8-pin VSSOP footprint saves space on printed circuit boards and allows ease of design in portable products.

The circuit shown in Figure 57, has the first op amp acting as a transimpedance amplifier with a gain of 47000, while the second stage provides a voltage gain of 10. This provides a total transimpedance gain of 470000 with a -3 dB bandwidth of about 1.5 MHz, for a total input capacitance of 50 pF. The frequency response for the circuit is shown in Figure 58

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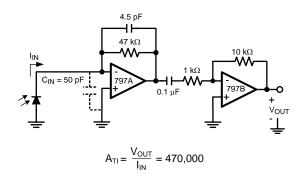


Figure 57. 1.5 MHz Transimpedance Amplifier with  $A_{TI} = 470000$ 

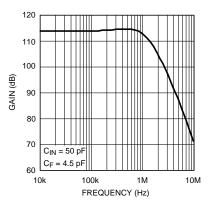


Figure 58. 1.5 MHz Transimpedance Amplifier Frequency Response

### SENSOR INTERFACES

The low input bias current and low input referred noise of the LMV796 and LMV797 make them ideal for sensor interfaces. These circuits are required to sense voltages of the order of a few  $\mu$ V and currents amounting to less than a nA hence, the op amp needs to have low voltage noise and low input bias current. Typical applications include infra-red (IR) thermometry, thermocouple amplifiers and pH electrode buffers. Figure 59 is an example of a typical circuit used for measuring IR radiation intensity, often used for estimating the temperature of an object from a distance. The IR sensor generates a voltage proportional to I, which is the intensity of the IR radiation falling on it. As shown in Figure 59, K is the constant of proportionality relating the voltage across the IR sensor (V<sub>IN</sub>) to the radiation intensity, I. The resistances R<sub>A</sub> and R<sub>B</sub> are selected to provide a high gain to amplify this voltage, while C<sub>F</sub> is added to filter out the high frequency noise.

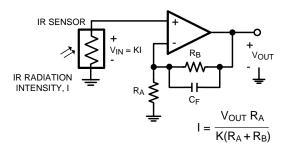


Figure 59. IR Radiation Sensor

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Changes from Revision C (March 2013) to Revision C



Page

Submit Documentation Feedback

Page



## **PACKAGING INFORMATION**

| Orderable Device | Status | Package Type | •       | Pins | •    | Eco Plan     | Lead finish/  | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|--------------|---------------|--------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty  | (2)          | Ball material | (3)                |              | (4/5)          |         |
|                  |        |              |         |      |      |              | (6)           |                    |              |                |         |
| LMV796MF/NOPB    | ACTIVE | SOT-23       | DBV     | 5    | 1000 | RoHS & Green | SN            | Level-1-260C-UNLIM | -40 to 125   | АТЗА           | Samples |
| LMV796MFX/NOPB   | ACTIVE | SOT-23       | DBV     | 5    | 3000 | RoHS & Green | SN            | Level-1-260C-UNLIM | -40 to 125   | АТЗА           | Samples |
| LMV796QMF/NOPB   | ACTIVE | SOT-23       | DBV     | 5    | 1000 | RoHS & Green | SN            | Level-1-260C-UNLIM | -40 to 125   | AD7A           | Samples |
| LMV796QMFX/NOPB  | ACTIVE | SOT-23       | DBV     | 5    | 3000 | RoHS & Green | SN            | Level-1-260C-UNLIM | -40 to 125   | AD7A           | Samples |
| LMV797MM/NOPB    | ACTIVE | VSSOP        | DGK     | 8    | 1000 | RoHS & Green | SN            | Level-1-260C-UNLIM | -40 to 125   | AU3A           | Samples |
| LMV797MMX/NOPB   | ACTIVE | VSSOP        | DGK     | 8    | 3500 | RoHS & Green | SN            | Level-1-260C-UNLIM | -40 to 125   | AU3A           | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



10-Dec-2020

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#### OTHER QUALIFIED VERSIONS OF LMV796, LMV796-Q1 :

- Catalog: LMV796
- Automotive: LMV796-Q1

NOTE: Qualified Version Definitions:

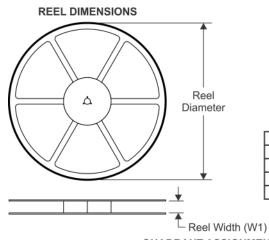
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects

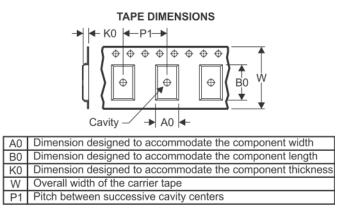
# PACKAGE MATERIALS INFORMATION

Texas Instruments

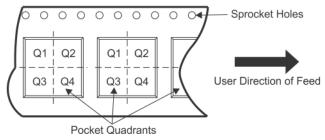
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## TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

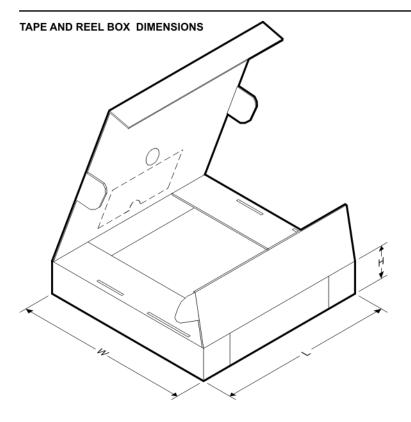


| Device          | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LMV796MF/NOPB   | SOT-23          | DBV                | 5 | 1000 | 178.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| LMV796MFX/NOPB  | SOT-23          | DBV                | 5 | 3000 | 178.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| LMV796QMF/NOPB  | SOT-23          | DBV                | 5 | 1000 | 178.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| LMV796QMFX/NOPB | SOT-23          | DBV                | 5 | 3000 | 178.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| LMV797MM/NOPB   | VSSOP           | DGK                | 8 | 1000 | 178.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LMV797MMX/NOPB  | VSSOP           | DGK                | 8 | 3500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |



# PACKAGE MATERIALS INFORMATION

29-Oct-2021



\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMV796MF/NOPB   | SOT-23       | DBV             | 5    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV796MFX/NOPB  | SOT-23       | DBV             | 5    | 3000 | 208.0       | 191.0      | 35.0        |
| LMV796QMF/NOPB  | SOT-23       | DBV             | 5    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV796QMFX/NOPB | SOT-23       | DBV             | 5    | 3000 | 208.0       | 191.0      | 35.0        |
| LMV797MM/NOPB   | VSSOP        | DGK             | 8    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV797MMX/NOPB  | VSSOP        | DGK             | 8    | 3500 | 367.0       | 367.0      | 35.0        |

# **DBV0005A**



# **PACKAGE OUTLINE**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.This drawing is subject to change without notice.Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



# **DBV0005A**

# **EXAMPLE BOARD LAYOUT**

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# **DBV0005A**

# **EXAMPLE STENCIL DESIGN**

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

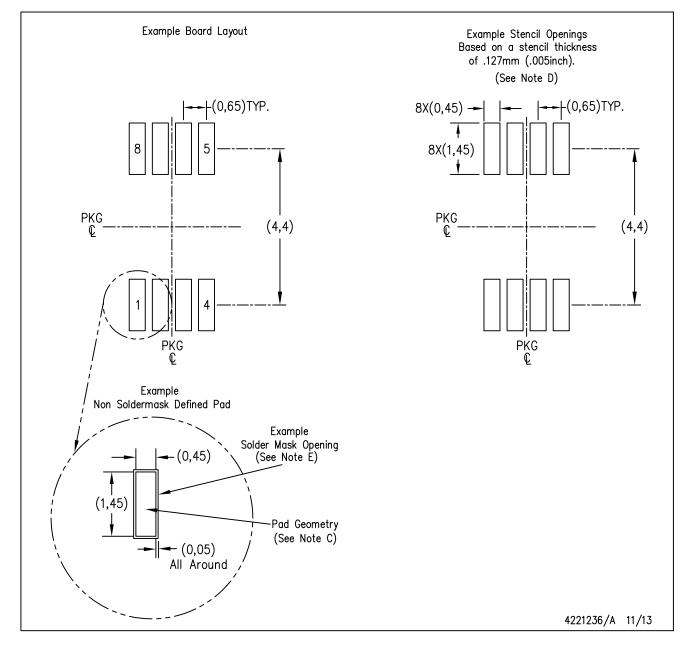
Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D> Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



# DGK (S-PDSO-G8)

# PLASTIC SMALL OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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